Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:	
Metal	
Overall Length:	
Between 0.170 inches and 0.210 inches	
Terminal Length:	
Between 0.500 inches and 0.750 inches	
Overall Diameter:	
Between 0.209 inches and 0.230 inches	
Internal Configuration:	
Junction contact	
Electrode Internally-electrically Connected To Case:	
Anode	
Mounting Method:	
Terminal	
Terminal Circle Diameter:	
0.100 inches	
Features Provided:	
Hermetically sealed case	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts Per Characteristic:	
1.5 forward voltage, peak	
Current Rating Per Characteristic:	
8.00 amperes source cutoff current outside diameter and 200.00 microamperes forward co	urrent, total rms preset
Maximum Operating Tempurature Per Measurement Point:	
150.0 degrees celsius ambient air	
Special Features:	
Junction pattern arrangement: pnpn	
Test Data Document:	
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., tha	
format; excludes commercial catalogs, industry directories, and similar trade publications	•••
environmental and performance requirements and test conditions that are shown as "typic	al", "average", "", etc.).
Terminal Type And Quantity:	
3 uninsulated wire lead	
Specification Data:	
81349-mil-s-19500/419 government specification	
Shelf Life:	
N/a	
Unit Of Measure:	
 Demilitarization:	
No	
Fiig:	
A110a0	